

Features

- · Operated at Low Logic Level Gate Drive
- N-Channel Switch with Low R_{DS(on)}
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance:238°C/W Junction to Ambient(Steady-State)⁽²⁾

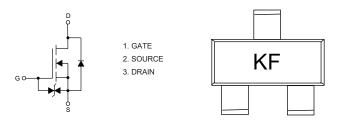
Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	V _{DS}	20	V		
Gate-Source Volltage	V _{GS}	±12	V		
Continuous Drain Current	T _A =25°C		0.75	A	
	T _A =100°C	- I _D	0.47		
Pulsed Drain Current ⁽³⁾	I _{DM}	1.8	А		
Total Power Dissipation ⁽⁴⁾		P _D	0.5	W	

Note:

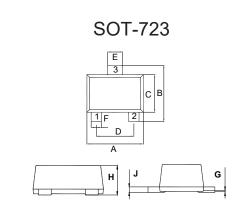
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The Power dissipation P_{DSM} is based on R_{θJA} t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_{D} is based on max. junction temperature, using junction to ambient thermal resistance.

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Internal Structure and Marking Code

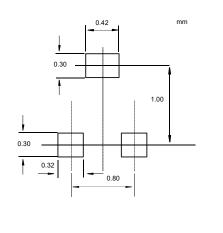


N-CHANNEL MOSFET



DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.043	0.051	1.10	1.30	
В	0.043	0.051	1.10	1.30	
С	0.028	0.035	0.70	0.90	
D	0.031		0.80		TYP.
Е	0.009	0.017	0.22	0.42	
F	0.005	0.013	0.12	0.32	
G	0.000	0.002	0.00	0.05	
Н	0.017	0.021	0.43	0.54	
J	0.003	0.006	0.08	0.15	

Suggested Solder Pad Layout



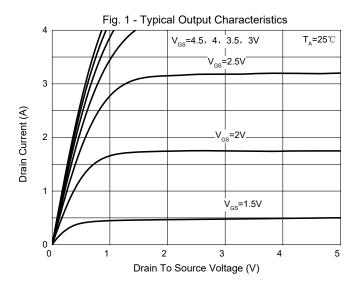


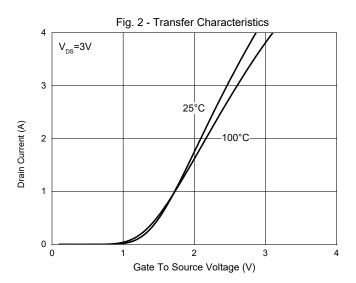
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

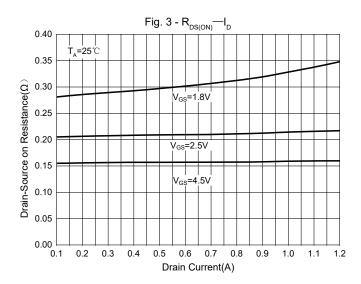
Parameter	ter Symbol Test Conditions		Min	Тур	Max	Unit	
Static Characteristics	1						
Drain-Source Breakdown Voltage	Drain-Source Breakdown Voltage V _{(BR)DSS}		20			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±10V			±10		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V, Ta=25 °C			1.0	uA	
		V _{DS} =20V, V _{GS} =0V, Ta=125 °C			2.0		
Gate-Threshold Voltage	age $V_{GS(th)}$ $V_{DS}=V_{GS}$, $I_D=250\mu A$ 0.35		0.35		1.0	V	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =650mA	0.38		0.38	Ω	
		V _{GS} =2.5V, I _D =550mA			0.45		
		V _{GS} =1.8V, I _D =450mA			0.80	=	
Gate Resistance	R _g	F=1 MHz, Open drain		72.1		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				0.15	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =150mA			1.2	V	
Reverse Recovery Time	t _{rr}	I _F =0.5A, dI _F /dt=100A/μs		8.8		ns	
Reverse Recovery Charge	Q _{rr}	- i _F =0.3Δ, αi _F /αί=100Δ/μ3		1.4		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			79	120		
Output Capacitance	C _{oss}	V _{DS} =16V,V _{GS} =0V,f=1MHz		13	20	pF	
Reverse Transfer Capacitance	C _{rss}			9	15		
Total Gate Charge	Qg			0.9			
Gate-Source Charge	Q _{gs}	V _{DS} =10V,V _{GS} =4.5V,I _D =1A		0.15		nC	
Gate-Drain Charge	Q_{gd}			0.24			
Turn-On Delay Time	t _{d(on)}			6.7			
Turn-On Rise Time	t _r	V _{DD} =10V,V _{GS} =4.5V,		4.8		no	
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =10 Ω , I_D =500mA		17.3		ns	
Turn-Off Fall Time	t _f			7.4			

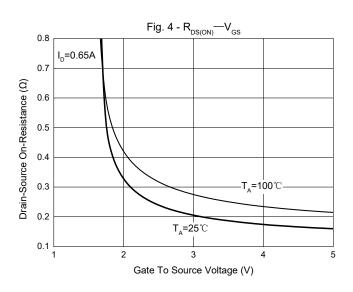


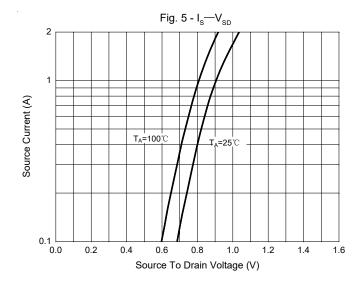
Curve Characteristics

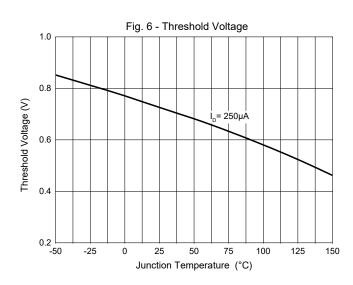






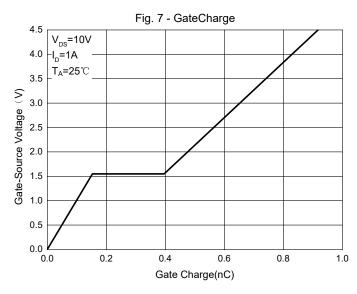


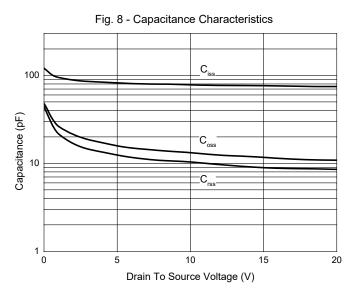


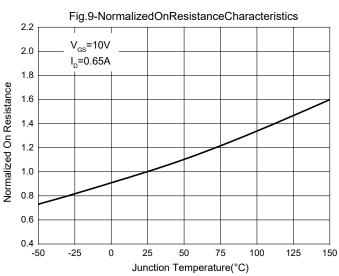


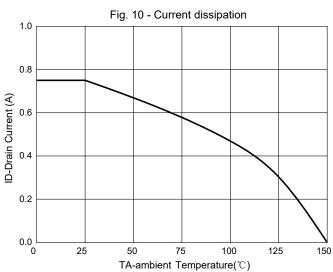


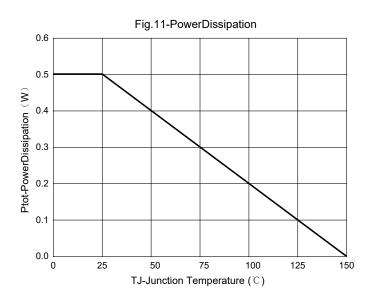
Curve Characteristics





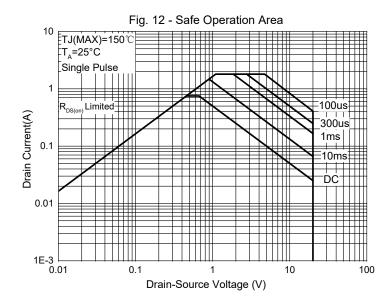


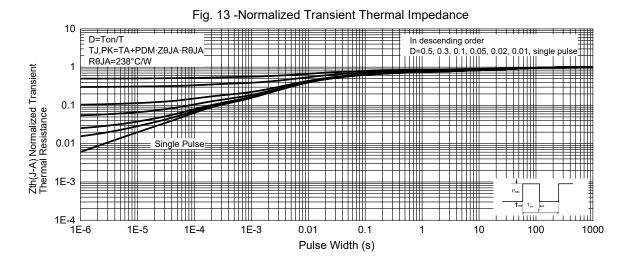






Curve Characteristics





Rev.4-1-12192022 5/6 MCCSEMI.COM



Ordering Information

Device	Packing
SI3134K-TP	Tape&Reel: 8Kpcs/Reel

Revision History

Datasheet status	Version No	Release date	Update content
New product datasheet	Rev4-1	20221219	

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